

/ Descriptions

WR0553 ММ SQS æ Ñ ç s ll 1 Silicon PNP transistor in a TO-220 Plastic Package.

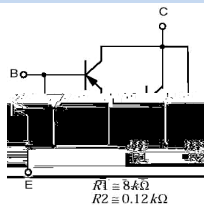
/ Features

g ll 0 ^ ñ ll ð" 1 000 3 ´ ll ç ` Ì WLS475W Ì
Monolithic construction with built in base-emitter shunt resistors, High DC current gain complement to TIP142T.

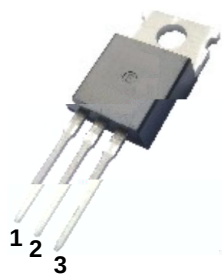
/ Applications

æ ñ ð Ì ÿ æ Ì 000 1 ó Æ Ì "Ω
Linear and switching industrial equipment.

/ Equivalent Circuit



/ Pinning



PIN1 χ Base PIN 2 χ Collector PIN 3 χ Emitter

/ h_{FE} Classifications & Marking

М 1 " See Marking Instructions.

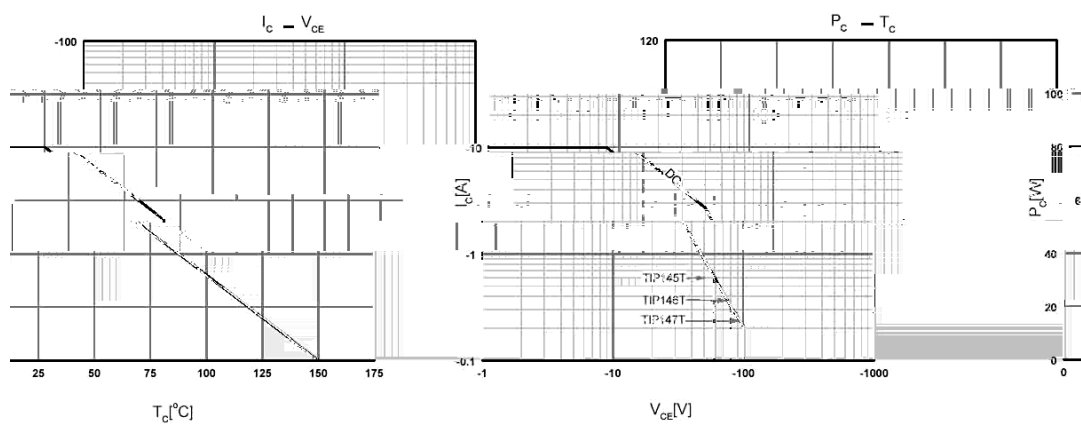
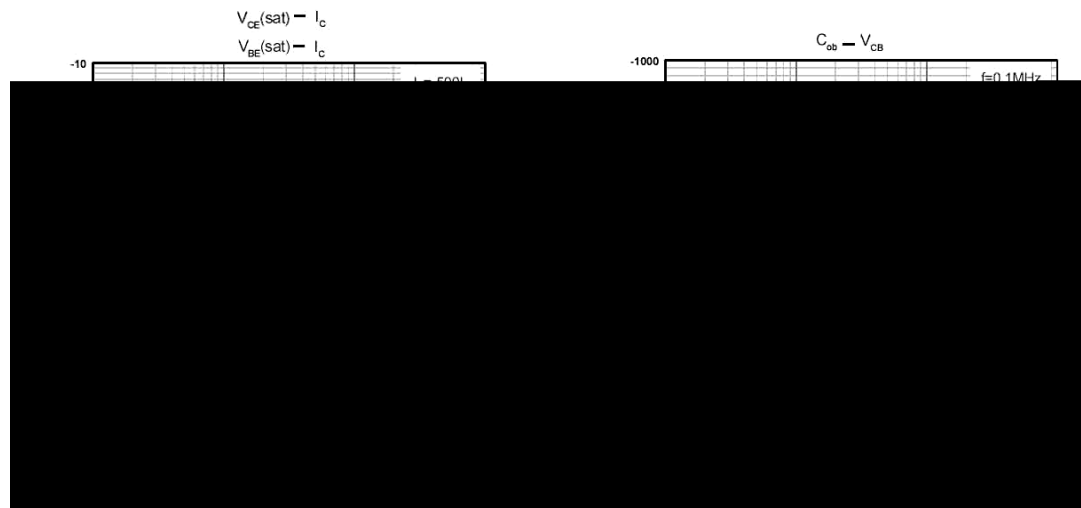
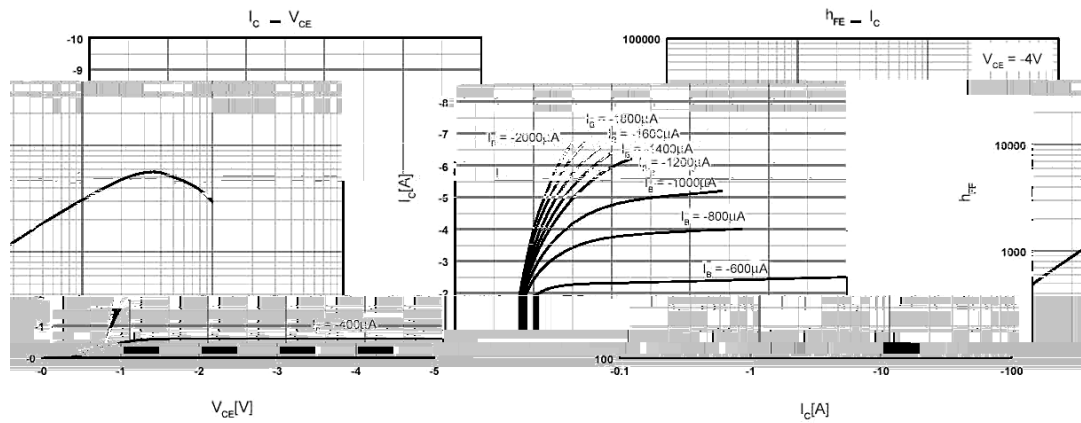
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-100	V
Collector to Emitter Voltage	V_{CEO}	-100	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-10	A
Peak Collector Current	I_{CP}	-15	A
Base Current - Continuous	I_B	-0.5	A
Collector Power Dissipation	$P_C(T_C=25)$	80	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 ~ 150	

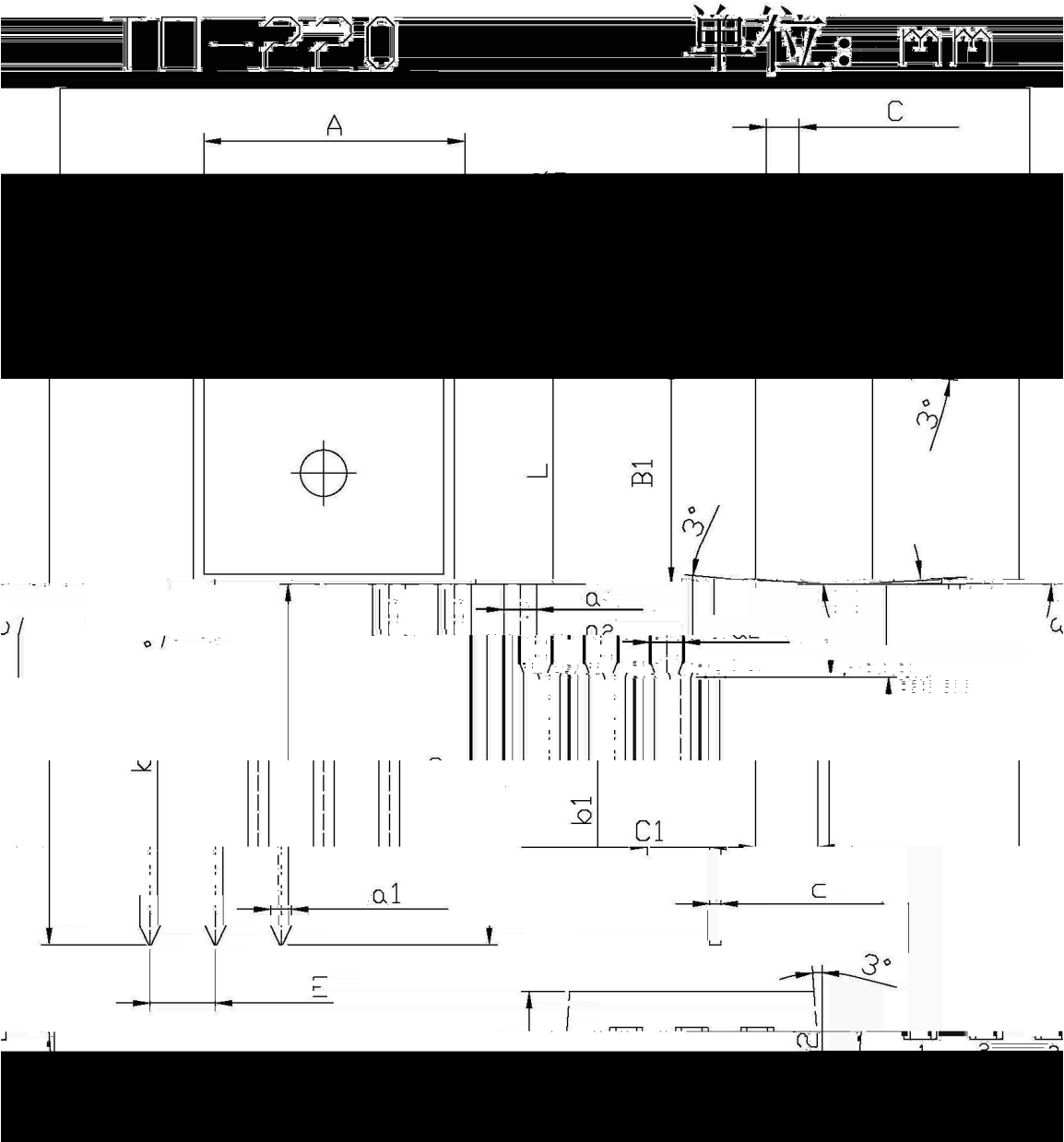
/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=-30mA$ $I_B=0$	-100			V
Collector Cut-Off Current	I_{CEO}	$V_{CE}=-50V$ $I_B=0$			-2.0	mA
Collector Cut-Off Current	I_{CBO}	$V_{CB}=-100V$ $I_E=0$			-1.0	mA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=-5.0V$ $I_C=0$			-2.0	mA
DC Current Gain	$h_{FE(1)}$	$V_{CE}=-4.0V$ $I_C=-5.0A$	1000			
	$h_{FE(2)}$	$V_{CE}=-4.0V$ $I_C=-10A$	500			
Collector to Emitter Saturation Voltage	$V_{CE(sat)(1)}$	$I_C=-5.0A$ $I_B=-10mA$			-2.0	V
	$V_{CE(sat)(2)}$	$I_C=-10A$ $I_B=-40mA$			-3.0	V
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=-10A$ $I_B=-40mA$			-3.5	V
Base to Emitter Voltage	V_{BE}	$V_{CE}=-4.0V$ $I_C=-10A$			-3.0	V
Delay Time	t_D	$V_{CC}=-3V$ $I_C=-5A$ $I_{B1}=-20mA$ $I_{B2}=20mA$ $R_L=6\Omega$		0.15		μs
Rise Time	t_R			0.55		μs
Storage Time	t_{STG}			2.5		μs
Fall Time	t_F			2.5		μs

/ Electrical Characteristic Curve

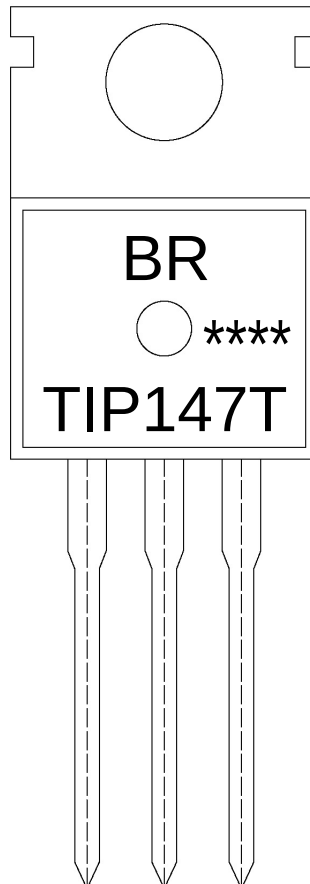


/ Package Dimensions



Dimensions in Millimeters			Dimensions in Millimeters		
Symbol	Min	Max	Symbol	Min	Max
A	9.0	9.4	C	1.2	1.4
B	3.56	3.64	B1	6.3	6.7
a	1.32	1.45	a1	0.4	0.6
b1	0.1	0.2	C1	0.1	0.2
E	1.45	1.55			

/ Marking Instructions



” X

EU X 𐀀 𐀁 𐀂 𐀃

WLS47:W X 𐀄 𐀅 𐀆 𐀇 𐀈

---- X 𐀉 𐀊 𐀋 𐀌 𐀍 𐀎 𐀏 𐀐 𐀑 𐀒 𐀓 𐀔 𐀕 𐀖 𐀗 𐀘 𐀙 𐀚 𐀛 𐀜 𐀝 𐀞 𐀟 𐀠 𐀡 𐀢 𐀣 𐀤 𐀥 𐀦 𐀧 𐀨 𐀩 𐀪 𐀫 𐀬 𐀭 𐀮 𐀯 𐀰 𐀱 𐀲 𐀳 𐀴 𐀵 𐀶 𐀷 𐀸 𐀹 𐀺 𐀻 𐀼 𐀽 𐀾 𐀿

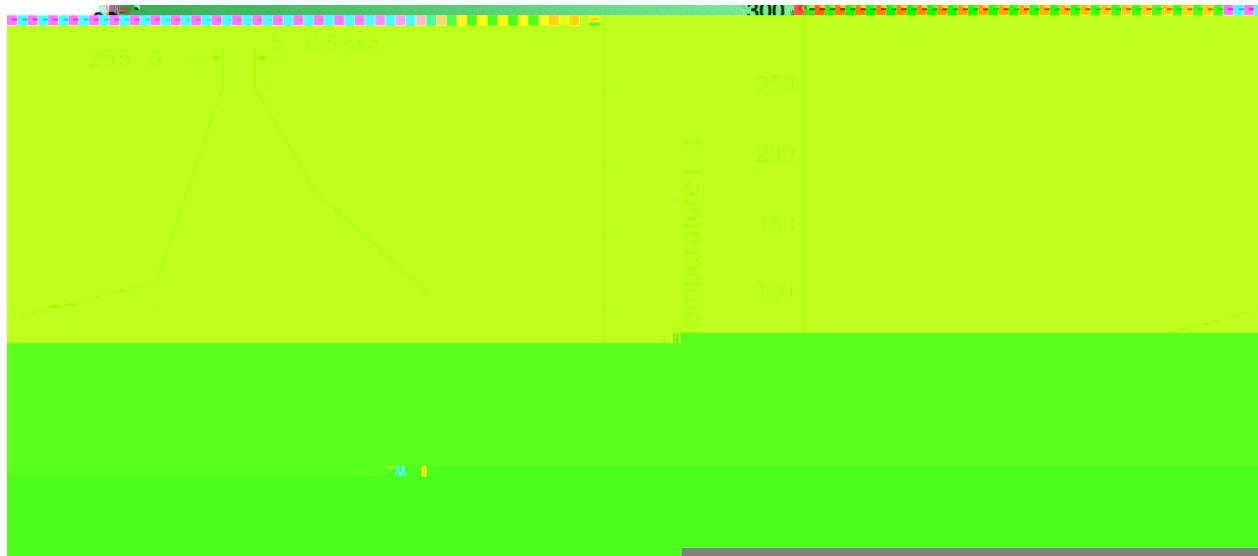
Note:

BR: Company Code

TIP147T: Product Type.

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



” X

- 1 25~150 ℃ , Time: 60~90sec;
- 2 255 ° 5 ℃ , Duration: 5 ° 0.5sec;
- 3 6 ℃ / min

Note:

- 1.Preheating:25~150 ℃ , Time:60~90sec.
- 2.Peak Temp.:255 ° 5 ℃ , Duration:5 ° 0.5sec.